NSN 5961-01-464-4127

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-464-4127 **Inclosure Material:** Glass **Overall Length:** 2.500 millimeters **Terminal Length:** 1.400 millimeters **Overall Width:** 1.100 millimeters **End Application:** 6625-01-443-0552 **Mounting Facility Quantity: Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 12.0 breakdown voltage, collector to emitter, sustained and 20.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 200.0 milliwatts small-signal output power, common-base preset **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 200.0 degrees celsius case **Special Features:** Uhf/microwave npn bjt **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No